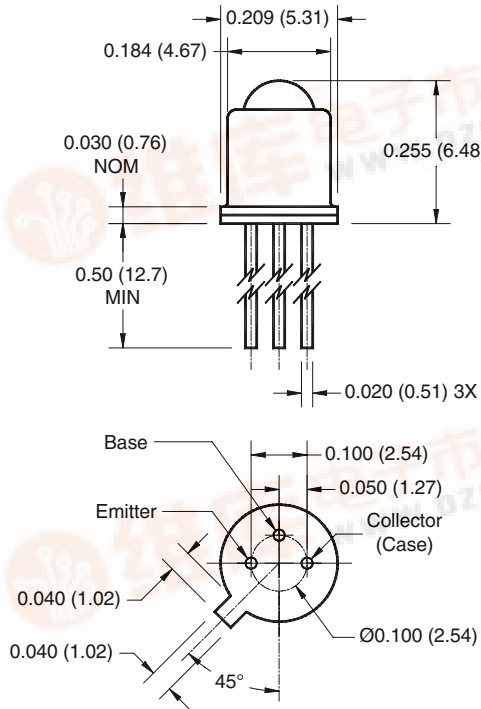


BPW36/BPW37 HERMETIC SILICON PHOTOTRANSISTOR

PACKAGE DIMENSIONS

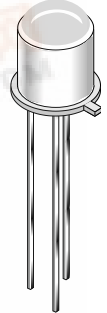


NOTES:

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of $\pm .010$ (.25) on all non-nominal dimensions unless otherwise specified.

FEATURES

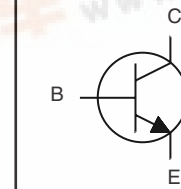
- Hermetically sealed package
- Narrow reception angle
- European "Pro Electron" registered



DESCRIPTION

- The BPW36/37 are silicon phototransistors mounted in narrow angle TO-18 packages.

SCHEMATIC



1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
3. RMA flux is recommended.
4. Methanol or isopropyl alcohols are recommended as cleaning agents.
5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
6. As long as leads are not under any stress or spring tension.
7. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	T _{OPR}	-65 to +125	°C
Storage Temperature	T _{STG}	-65 to +150	°C
Soldering Temperature (Iron) ^(3,4,5 and 6)	T _{SOL-I}	240 for 5 sec	°C
Soldering Temperature (Flow) ^(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C
Collector-Emitter Voltage	V _{CEO}	45	V
Collector-Base Voltage	V _{CBO}	45	V
Emitter-Base Voltage	V _{EBO}	5	V
Power Dissipation (T _A = 25°C) ⁽¹⁾	P _D	300	mW
Power Dissipation (T _C = 25°C) ⁽²⁾	P _D	600	mW

ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C) (All measurements made under pulse conditions)						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Collector-Emitter Breakdown	I _C = 10 mA, E _e = 0	BV _{CEO}	45	—	—	V
Emitter-Base Breakdown	I _E = 100 μA, E _e = 0	BV _{EBO}	5.0	—	—	V
Collector-Base Breakdown	I _C = 100 μA, E _e = 0	BV _{CBO}	45	—	—	V
Collector-Emitter Leakage	V _{CE} = 10 V, E _e = 0	I _{CEO}	—	—	100	nA
Reception Angle at 1/2 Sensitivity		θ	—	±10	—	Deg.
On-State Collector Current BPW36	E _e = 0.5 mW/cm ² V _{CE} = 5 V ⁽⁷⁾	I _{C(ON)}	1.0	—	—	mA
On-State Collector Current BPW37	E _e = 0.5 mW/cm ² V _{CE} = 5 V ⁽⁷⁾	I _{C(ON)}	0.5	—	—	mA
Turn-On Time	I _C = 2 mA, V _{CC} = 10 V R _L = 100 Ω	t _{on}	—	8	—	μs
Turn-Off Time	I _C = 2 mA, V _{CC} = 10 V R _L = 100 Ω	t _{off}	—	7	—	μs
Saturation Voltage	I _C = 1.0 mA, E _e = 3.0 mW/cm ²	V _{CE(SAT)}	—	—	0.40	V

TYPICAL PERFORMANCE CURVES

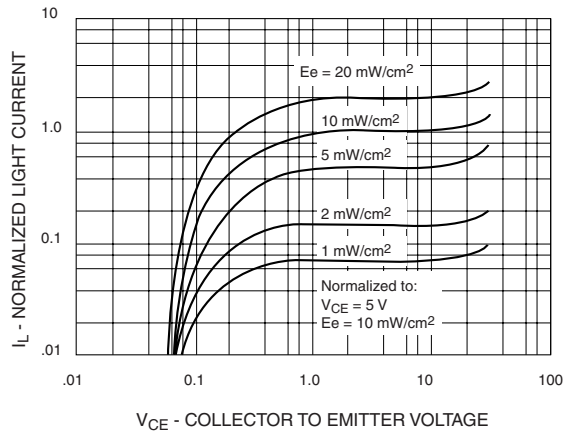


Fig. 1 Light Current vs. Collector to Emitter Voltage

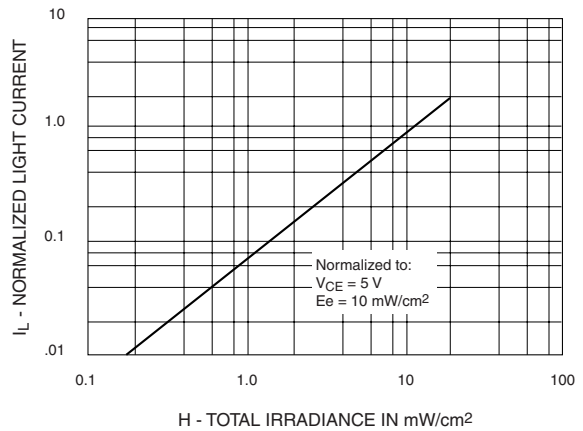


Fig. 2 Normalized Light Current vs. Radiation

TYPICAL PERFORMANCE CURVES

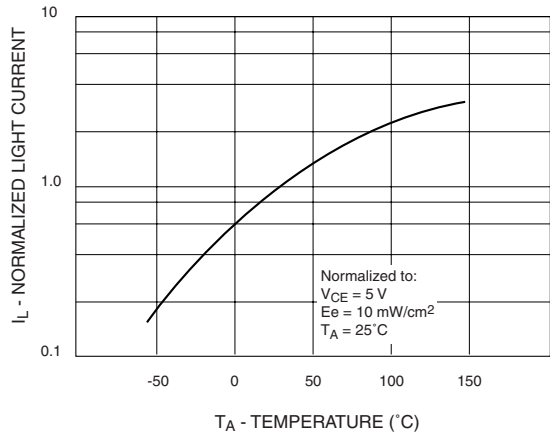


Fig. 3 Normalized Light Current vs. Temperature

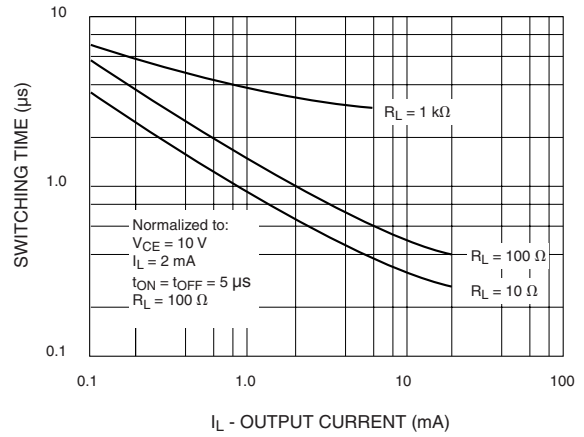


Fig. 4 Switching Times vs. Output Current

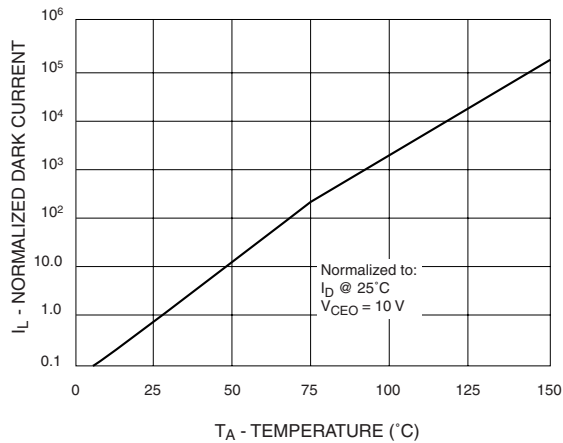


Fig. 5 Dark Current vs. Temperature

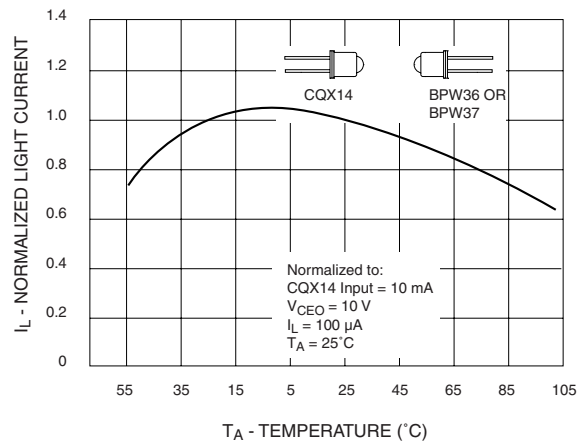


Fig. 6 Normalized Light Current vs. Temperature Both Emitter (CQX14) and Detector (BPW36 or BPW37) at Same Temperature



BPW36/BPW37

HERMETIC SILICON PHOTOTRANSISTOR

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